

D1FS4A**40V 1.5A****特長**

- 小型SMD
- 低 $V_F=0.45V$
- PRISMアバランシェ保証

Feature

- Small SMD
- Low $V_F=0.45V$
- PRISM Rating

用途

- スイッチング電源
- DC/DCコンバータ
- 家電、ゲーム、OA機器
- 通信、ポータブル機器

Main Use

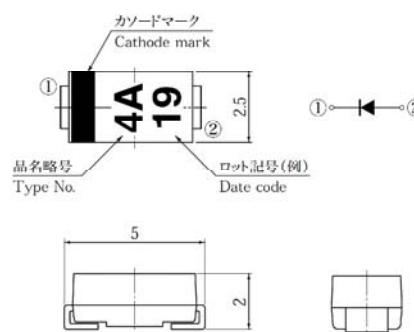
- Switching Regulator
- DC/DC Converter
- Home Appliance, Game, Office Automation
- Communication, Portable set

■外観図 OUTLINE

Package : 1F

Unit:mm

Weight 0.058g (Typ)



外形図については新電元Webサイト又は〈半導体製品一覧表〉をご参照下さい。捺印表示については捺印仕様をご確認下さい。

For details of the outline dimensions, refer to our web site or Semiconductor Short Form Catalog. As for the marking, refer to the specification "Marking, Terminal Connection".

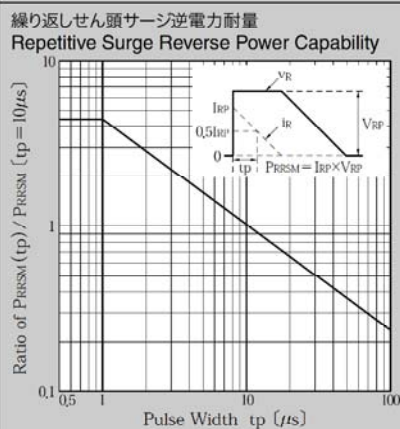
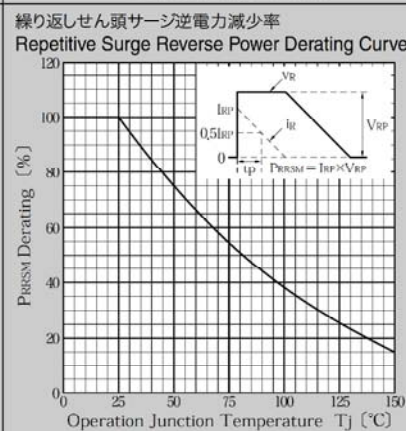
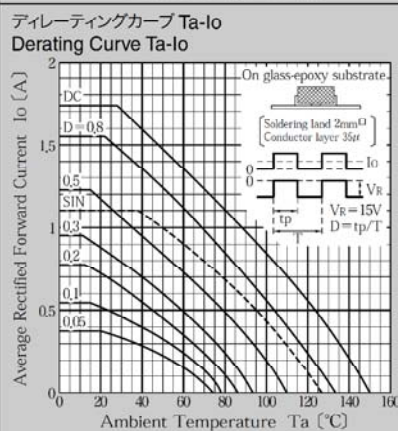
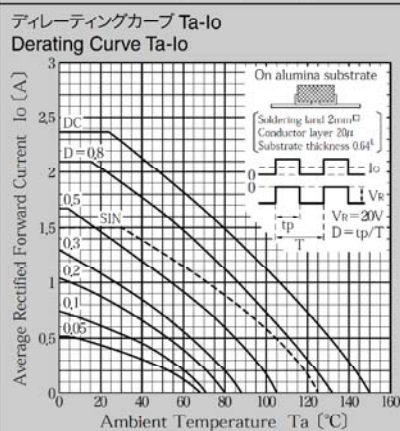
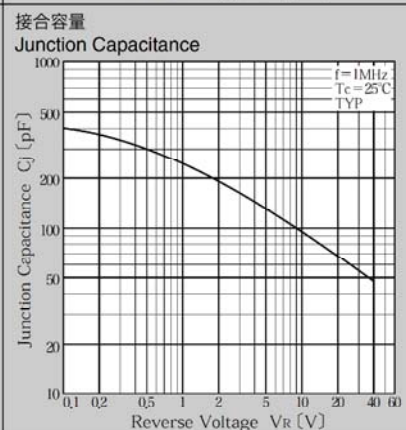
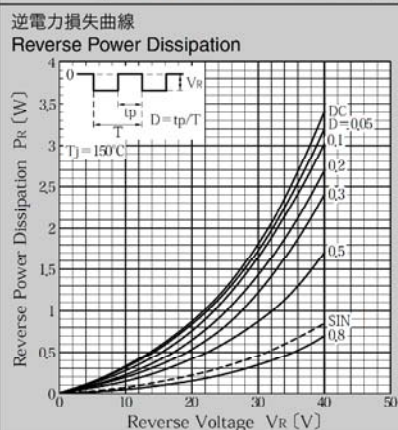
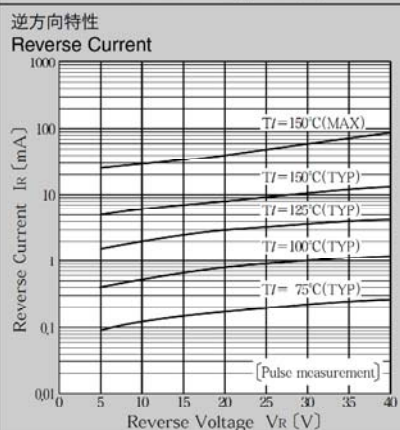
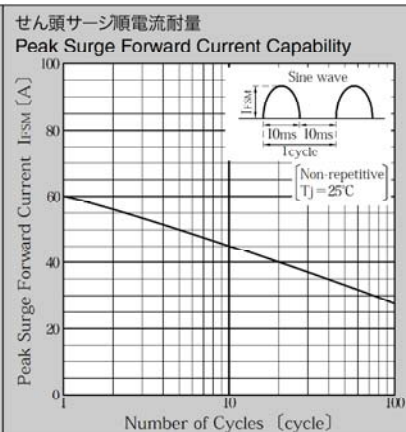
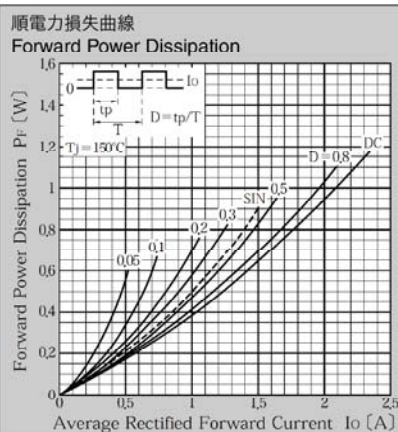
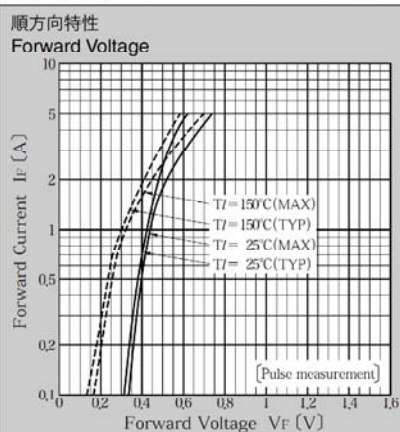
■定格表 RATINGS**●絶対最大定格 Absolute Maximum Ratings (指定のない場合 $T_I = 25^\circ C$)**

項目 Item	記号 Symbol	条件 Conditions	品名 Type No.	D1FS4A	単位 Unit
保存温度 Storage Temperature	T_{stg}			-55~150	$^\circ C$
接合部温度 Operation Junction Temperature	T_j			150	$^\circ C$
せん頭逆電圧 Maximum Reverse Voltage	V_{RM}			40	V
繰り返しせん頭サージ逆電圧 Repetitive Peak Surge Reverse Voltage	V_{RRSM}	パルス幅0.5ms, duty 1/40 Pulse width 0.5ms, duty 1/40		45	V
出力電流 Average Rectified Forward Current	I_o	50Hz正弦波, 抵抗負荷 50Hz sine wave, Resistance load	$T_a = 28^\circ C$ アルミナ基板実装 On alumina substrate	1.5	A
			$T_a = 36^\circ C$ プリント基板実装 On glass-epoxy substrate	1.1	
せん頭サージ順電流 Peak Surge Forward Current	I_{FSM}	50Hz正弦波, 非繰り返し1サイクルせん頭値, $T_j = 25^\circ C$ 50Hz sine wave, Non-repetitive 1 cycle peak value, $T_j = 25^\circ C$		60	A
繰り返しせん頭サージ逆電力 Repetitive Peak Surge Reverse Power	P_{RRSM}	パルス幅10 μs , $T_j = 25^\circ C$ Pulse width 10 μs , $T_j = 25^\circ C$		160	W

●電氣的・熱的特性 Electrical Characteristics (指定のない場合 $T_I = 25^\circ C$)

順電圧 Forward Voltage	V_F	$I_F = 1.1A$, パルス測定 Pulse measurement	MAX 0.45	V
		$I_F = 1.5A$, パルス測定 Pulse measurement	MAX 0.48	
逆電流 Reverse Current	I_R	$V_R = V_{RM}$, パルス測定 Pulse measurement	MAX 2	mA
接合容量 Junction Capacitance	C_j	$f = 1MHz$, $V_R = 10V$	TYP 95	pF
熱抵抗 Thermal Resistance	θ_{jl}	接合部・リード間 Junction to lead	MAX 23	$^\circ C/W$
	θ_{ja}	接合部・周囲間 Junction to ambient	アルミナ基板実装 On alumina substrate	
			プリント基板実装 On glass-epoxy substrate	

■特性図 CHARACTERISTIC DIAGRAMS



* Sine waveは50Hzで測定しています。
 * 50Hz sine wave is used for measurements.
 * 半導体製品の特性は一般的にバラツキを持っています。
 Typical is a statistical average of the device's ability.
 * Semiconductor products generally have characteristic variation.
 Typical is a statistical average of the device's ability.